



BCP 54/ 55/ 56

NPN MEDIUM POWER TRANSISTORS IN SOT223

Features

- BV_{CEO} > 45V, 60V & 80V
- I_C = 1A High Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Gain Groups 10 and 16
- Complementary PNP Types: BCP51, 52 and 53
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate) (3)

Applications

Medium Power Switching or Amplification Applications

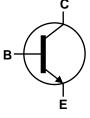
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AF Driver and Output Stages

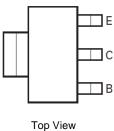


SOT223

Top View



Device Symbol



Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per ree	
BCP54TA	AEC-Q101	BCP 54	7	12	1,000	
BCP5410TA	AEC-Q101	BCP 5410	7	12	1,000	
BCP5416TA	AEC-Q101	BCP 5416	7	12	1,000	
BCP5416QTA	Automotive	BCP 5416	7	12	1,000	
BCP55TA	AEC-Q101	BCP 55	7	12	1,000	
BCP5510TA	AEC-Q101	BCP 5510	7	12	1,000	
BCP5516TA	AEC-Q101	BCP 5516	7	12	1,000	
BCP56TA	AEC-Q101	BCP 56	7	12	1,000	
BCP5610TA	AEC-Q101	BCP 5610	7	12	1,000	
BCP5616TA	AEC-Q101	BCP 5616	7	12	1,000	
BCP5616TC	AEC-Q101	BCP 5616	13	12	4,000	
BCP5616QTA	Automotive	Refer to http://diodes.com/datasheets/BCP5616Q.pdf				
BCP5616QTC	Automotive	Refer to http://diodes.com/datasheets/BCP5616Q.pdf				

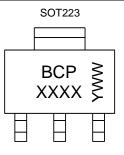
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



BCP = Product Type Marking Code, Line 1

XXXX = Product Type Marking Code, Line 2 as follows:

BCP54 = 54 BCP5410 = 5410 BCP5416 = 5416

BCP55 = 55 BCP5510 = 5510 BCP5516 = 5516

BCP56 = 56 BCP5610 = 5610 BCP5616 = 5616

YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W =$ Week Code (01~53)

BCP 54 / 55 / 56 Datasheet Number: DS35367 Rev. 6 - 2 1 of /

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP54	BCP55	BCP56	Unit
Collector-Base Voltage	V _{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V _{EBO}	5			V
Continuous Collector Current	lc	1			А
Peak Pulse Collector Current	I _{CM}				
Continuous Base Current	IB	100			mA
Peak Pulse Base Current	I _{BM}				

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	PD	2	W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	62	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R _{0JL}	19.4	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

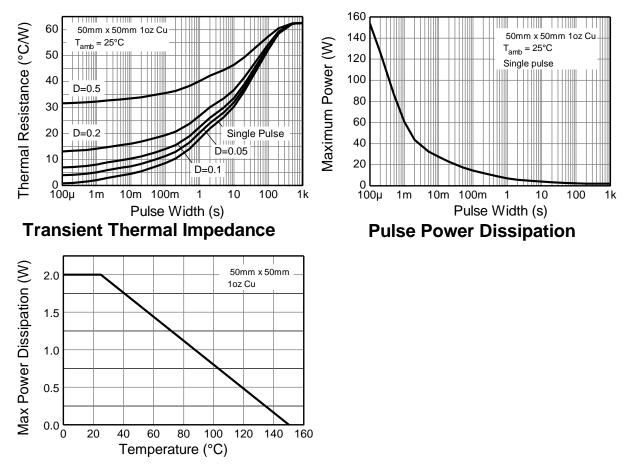
Notes: 6. For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

7. Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



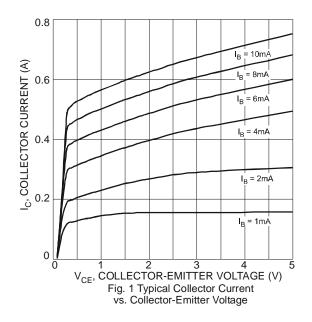
Derating Curve

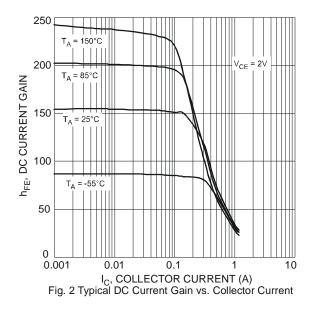


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BCP54 BCP55 BCP56	BV _{CBO}	45 60 100		-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BCP54 BCP55 BCP56	BV _{CEO}	45 60 80		-	v	I _C = 10mA
Emitter-Base Breakdown Voltage		BV _{EBO}	5	-	-	V	I _E = 10μΑ
Collector Cut-Off Current		I _{CBO}	-	-	0.1 20	μA	V _{CB} = 30V V _{CB} = 30V, T _A = +150°C
Emitter Cut-Off Current		I _{EBO}	-	-	20	nA	$V_{EB} = 4V$
Static Forward Current Transfer Ratio (Note 9)	All versions	b	25 40 25	-	- 250 -	_	$I_{C} = 5mA, V_{CE} = 2V$ $I_{C} = 150mA, V_{CE} = 2V$ $I_{C} = 500mA, V_{CE} = 2V$
	10 gain grp	h _{FE}	63	-	160		$I_{C} = 150 \text{mA}, V_{CE} = 2 \text{V}$
	16 gain grp		100	-	250		$I_{C} = 150 \text{mA}, V_{CE} = 2 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)		V _{CE(sat)}	-	-	0.5	V	$I_{\rm C} = 500 {\rm mA}, I_{\rm B} = 50 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 9)		V _{BE(on)}	-	-	1.0	V	$I_{C} = 500 \text{mA}, V_{CE} = 2 \text{V}$
Transition Frequency		f⊤	150	-	-	MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output Capacitance	Cobo	-	-	25	pF	V _{CB} = 10V, f = 1MHz	

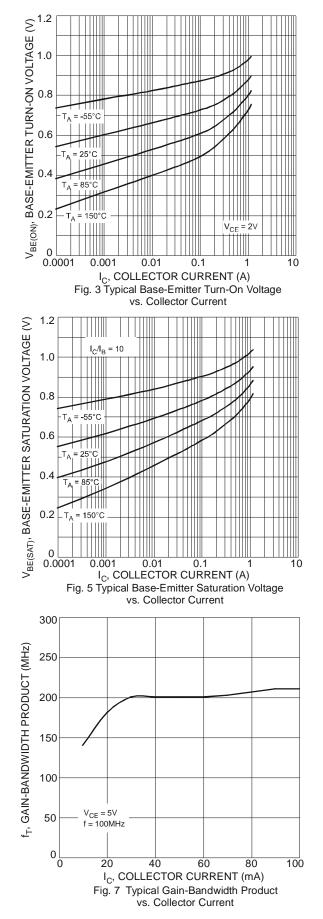
Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

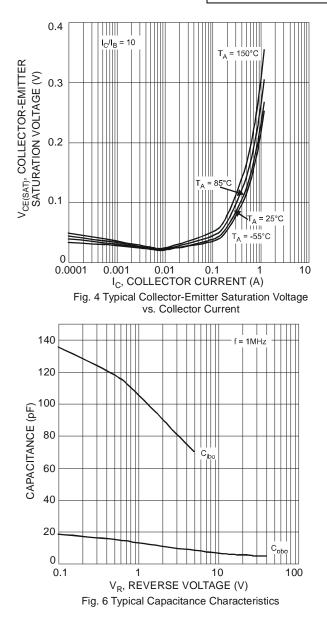






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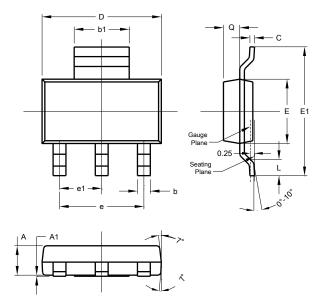






Package Outline Dimensions

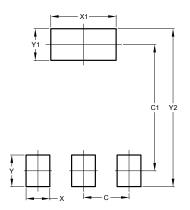
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
e	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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